

## General Description

MIC4451 and MIC4452 CMOS MOSFET drivers are robust, efficient, and easy to use. The MIC4451 is an inverting driver, while the MIC4452 is a non-inverting driver.

Both versions are capable of 12A (peak) output and can drive the largest MOSFETs with an improved safe operating margin. The MIC4451/4452 accepts any logic input from 2.4V to  $V_S$  without external speed-up capacitors or resistor networks. Proprietary circuits allow the input to swing negative by as much as 5V without damaging the part. Additional circuits protect against damage from electrostatic discharge.

MIC4451/4452 drivers can replace three or more discrete components, reducing PCB area requirements, simplifying product design, and reducing assembly cost.

Modern Bipolar/CMOS/DMOS construction guarantees freedom from latch-up. The rail-to-rail swing capability of CMOS/DMOS insures adequate gate voltage to the MOSFET during power up/down sequencing. Since these devices are fabricated on a self-aligned process, they have very low crossover current, run cool, use little power, and are easy to drive.

Data sheets and support documentation can be found on Micrel's web site at: [www.micrel.com](http://www.micrel.com).

## Features

- BiCMOS/DMOS construction
- Latch-up proof: fully-isolated process is inherently immune to any latch-up
- Input will withstand negative swing of up to 5V
- Matched rise and fall times: 25ns
- High peak output current: 12A peak
- Wide operating range: 4.5V to 18V
- High capacitive load drive: 62,000Pf
- Low delay time: 30ns (typ.)
- Logic high input for any voltage from 2.4V to  $V_S$
- Low supply current 450 $\mu$ A with logic 1 input
- Low output impedance: 1.0 $\Omega$
- Output voltage swing to within 25mV of GND or  $V_S$
- Low equivalent input capacitance (typ.): 7pF

## Applications

- Switch mode power supplies
- Motor controls
- Pulse transformer driver
- Class-D switching amplifiers
- Line drivers
- Driving MOSFET or IGBT parallel chip modules
- Local power ON/OFF switch
- Pulse generators

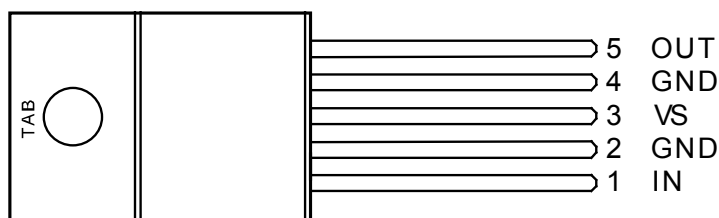
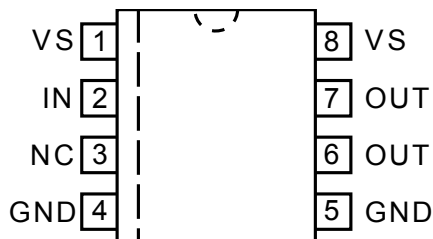
## Functional Diagram



## Ordering Information

Part Number		Temperature Range	Package	Configuration
Standard	Pb-Free			
-	MIC4451YN	-40°C to +85°C	8-Pin Plastic DIP	Inverting
MIC4451BM	MIC4451YM	-40°C to +85°C	8- Pin SOIC	Inverting
-	MIC4451ZT	0°C to +70°C	5- Pin TO-220	Inverting
-	MIC4452YN	-40°C to +85°C	8- Pin Plastic DIP	Non-Inverting
MIC4452BM	MIC4452YM	-40°C to +85°C	8- Pin SOIC	Non-Inverting
-	MIC4452ZT	0°C to +70°C	5- Pin TO-220	Non-Inverting
-	MIC4452VM	-40°C to +125°C	8- Pin SOIC	Non-Inverting

## Pin Configurations



## Pin Description

Pin Number T0-220-5	Pin Number DIP, SOIC	Pin Name	Pin Function
1	2	IN	Control Input.
2, 4	4, 5	GND	Ground: Duplicate Pins must be externally connected together.
3, TAB	1, 8	V <sub>s</sub>	Supply Input: Duplicate pins must be externally connected together.
5	6, 7	OUT	Output: Duplicate pins must be externally connected together.
	3	NC	Not Connected.

### Absolute Maximum Ratings<sup>(1, 2)</sup>

Supply Voltage .....	20V
Input Voltage .....	$V_S + 0.3V$ to GND $-5V$
Input Current ( $V_{IN} > V_S$ ) .....	5mA
Power Dissipation, $T_{AMBIENT} \leq 25^\circ C$	
PDIP .....	960mW
SOIC .....	1040mW
5-Pin TO-220 .....	2W
Power Dissipation, $T_{CASE} \leq 25^\circ C$	
5-Pin TO-220 .....	12.5W
Derating Factors (to Ambient)	
PDIP .....	7.7mW/ $^\circ C$
SOIC .....	8.3mW/ $^\circ C$
5-Pin TO-220 .....	17mW/ $^\circ C$
Storage Temperature .....	$-65^\circ C$ to $+150^\circ C$
Lead Temperature(10s) .....	300 $^\circ C$

### Operating Ratings

Operating Temperature (Chip) .....	150 $^\circ C$
Operating Temperature (Ambient)	
Z Version .....	0 $^\circ C$ to $+70^\circ C$
Y Version .....	$-40^\circ C$ to $+85^\circ C$
V Version .....	$-40^\circ C$ to $+125^\circ C$
Thermal Impedances (To Case)	
5-Pin TO-220(θJC) .....	10 $^\circ C/W$

### Electrical Characteristics<sup>(3)</sup>

( $T_A = 25^\circ C$ , with  $4.5V \leq V_S \leq 18V$  unless otherwise specified.)

Symbol	Parameter	Condition	Min.	Typ.	Max.	Units
<b>Input</b>						
$V_{IH}$	Logic 1 Input Voltage		2.4	1.3		V
$V_{IL}$	Logic 0 Input Voltage			1.1	0.8	V
$V_{IN}$	Input Voltage Range		-5		$V_S + .3$	V
$I_{IN}$	Input Current	$0 \leq V_{IN} \leq V_S$	-10		10	$\mu A$
<b>Output</b>						
$V_{OH}$	High Output Voltage	See Figure 1	$V_S - .025$			V
$V_{OL}$	Low Output Voltage	See Figure 1			0.025	V
$R_O$	Output Resistance, Output High	$I_{OUT} = 10mA, V_S = 18V$		0.6	1.5	$\Omega$
$R_O$	Output Resistance, Output Low	$I_{OUT} = 10mA, V_S = 18V$		0.8	1.5	$\Omega$
$I_{PK}$	Peak Output Current	$V_S = 18V$ (See Figure 6)		12		A
$I_{DC}$	Continuous Output Current		2			A
$I_R$	Latch-up Protection Withstand Reverse Current	Duty Cycle $\leq 2\%$ $t \leq 300\mu s$	>1500			mA
<b>Switching Time<sup>(3)</sup></b>						
$t_R$	Rise Time	Test Figure 1, $C_L = 15,000pF$		20	40	ns
$t_F$	Fall Time	Test Figure 1, $C_L = 15,000pF$		24	50	ns
$t_{D1}$	Delay Time	Test Figure 1		25	50	ns
$t_{D2}$	Delay Time	Test Figure 1		40	60	ns
<b>Power Supply</b>						
$I_S$	Power Supply Current	$V_{IN} = 3V$ $V_{IN} = 0V$		0.4 80	1.5 150	mA $\mu A$
$V_S$	Operating Input Voltage		4.5			V

## Electrical Characteristics

(Over operating temperature range with  $4.5V \leq V_S \leq 18V$  unless otherwise specified.)

Symbol	Parameter	Condition	Min.	Typ.	Max.	Units
<b>Input</b>						
$V_{IH}$	Logic 1 Input Voltage		2.4			V
$V_{IL}$	Logic 0 Input Voltage				0.8	V
$V_{IN}$	Input Voltage Range		-5		$V_S + .3$	V
$I_{IN}$	Input Current	$0 \leq V_{IN} \leq V_S$	-10		10	$\mu A$
<b>Output</b>						
$V_{OH}$	High Output Voltage	See Figure 1	$V_S - .025$			V
$V_{OL}$	Low Output Voltage	See Figure 1			0.025	V
$R_O$	Output Resistance, Output High	$I_{OUT} = 10mA, V_S = 18V$			2.2	$\Omega$
$R_O$	Output Resistance, Output Low	$I_{OUT} = 10mA, V_S = 18V$			2.2	$\Omega$
<b>Switching Time <sup>(3)</sup></b>						
$t_R$	Rise Time	Test Figure 1, $C_L = 15,000pF$			50	ns
$t_F$	Fall Time	Test Figure 1, $C_L = 15,000pF$			60	ns
$t_{D1}$	Delay Time	Test Figure 1			65	ns
$t_{D2}$	Delay Time	Test Figure 1			80	ns
<b>Power Supply</b>						
$I_S$	Power Supply Current	$V_{IN} = 3V$ $V_{IN} = 0V$			3 0.4	mA
$V_S$	Operating Input Voltage		4.5		18	V

### Notes:

- Functional operation above the absolute maximum stress ratings is not implied.
- Static-sensitive device. Store only in conductive containers. Handling personnel and equipment should be grounded to prevent damage from static discharge.
- Specification for packaged product only.

**Test Circuits**

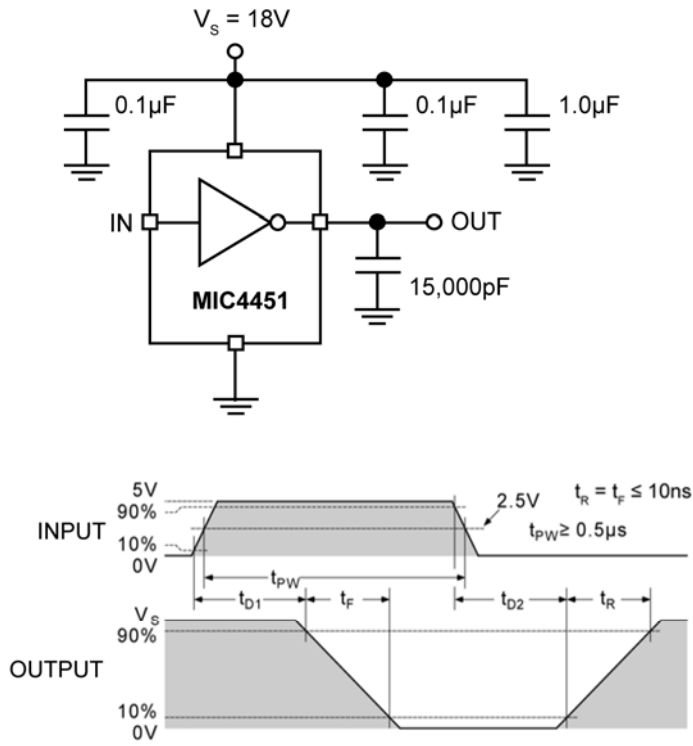


Figure 1. Inverting Driver Switching Time

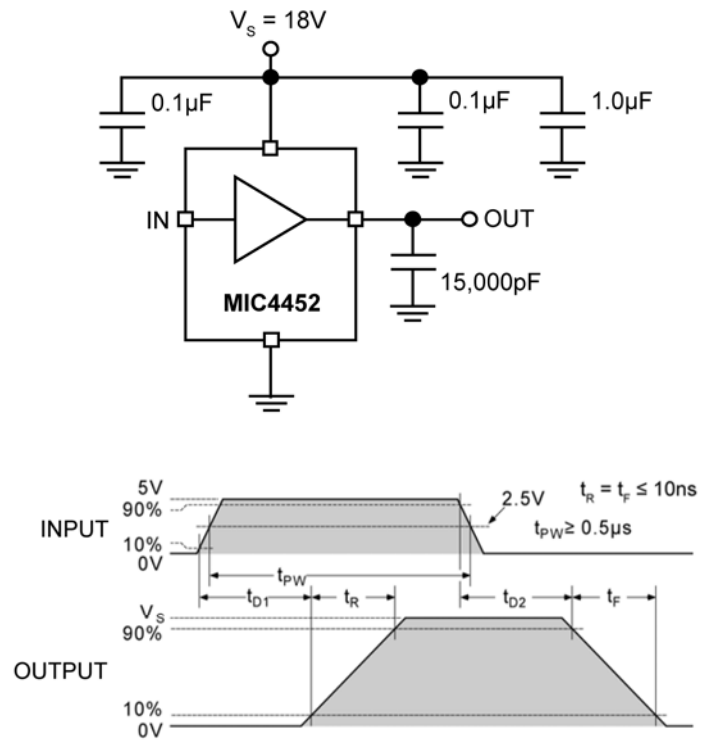


Figure 2. Noninverting Driver Switching Time

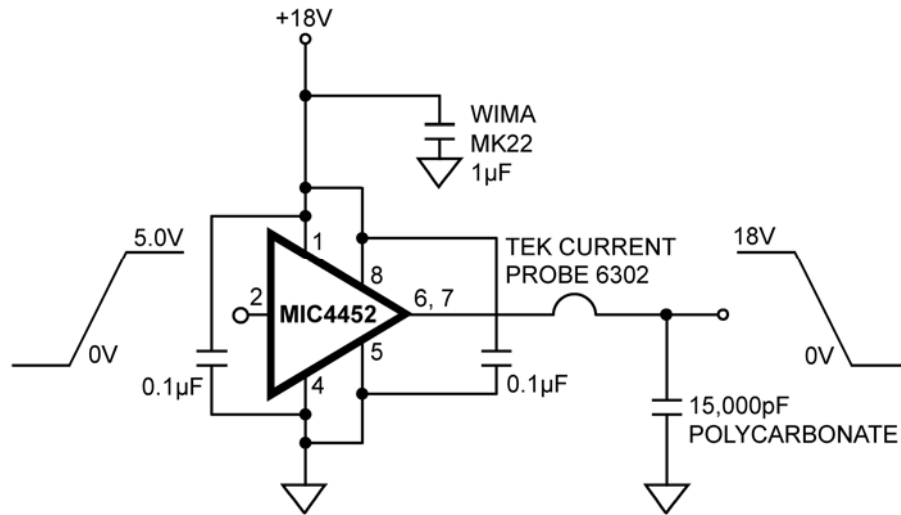
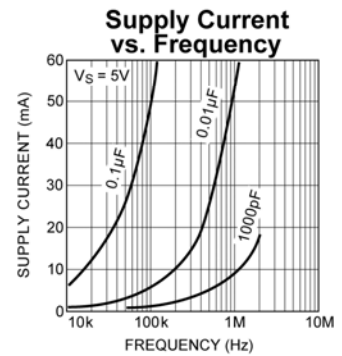
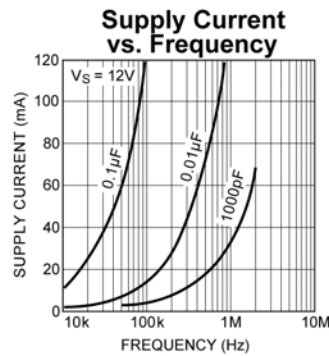
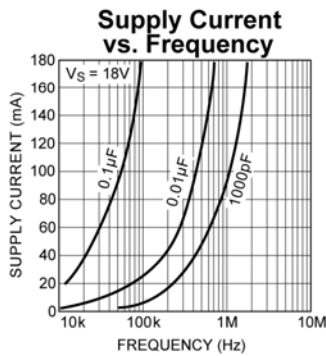
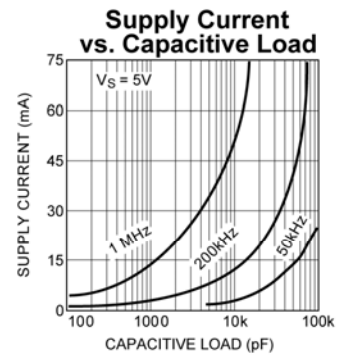
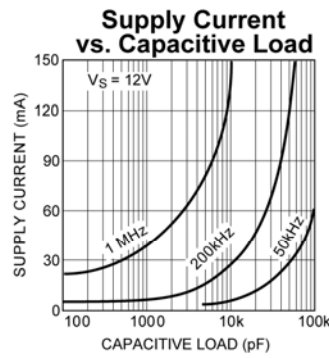
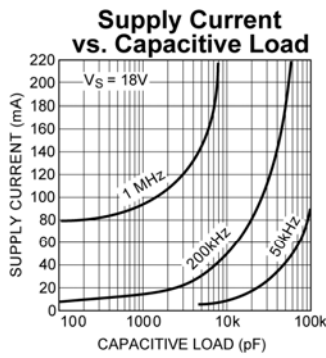
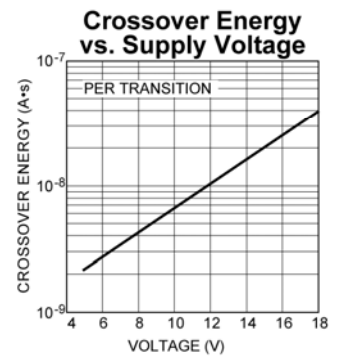
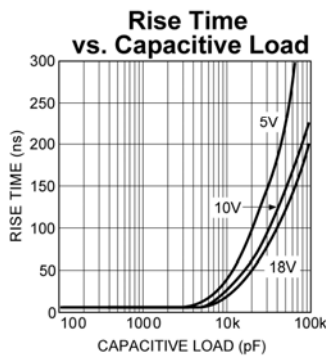


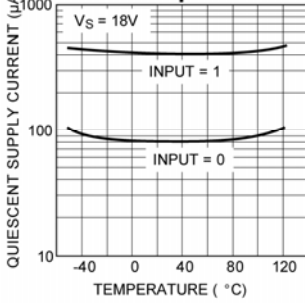
Figure 3. Peak Output Current Test Circuit

# Typical Characteristics

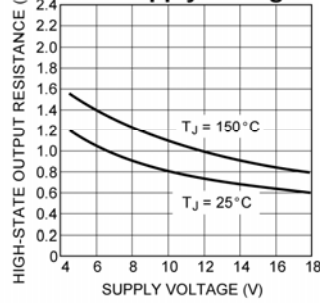


## Typical Characteristics Curves (Continued)

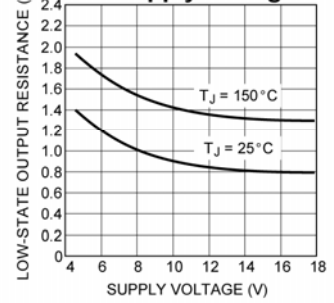
**Quiescent Supply Current vs. Temperature**



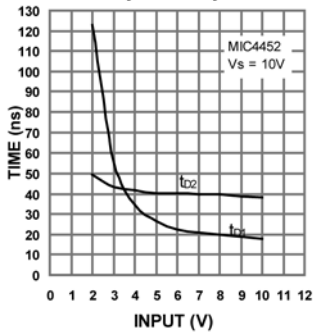
**High-State Output Resist. vs. Supply Voltage**



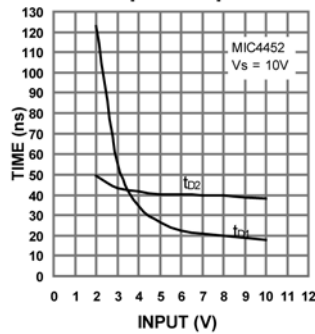
**Low-State Output Resist. vs. Supply Voltage**



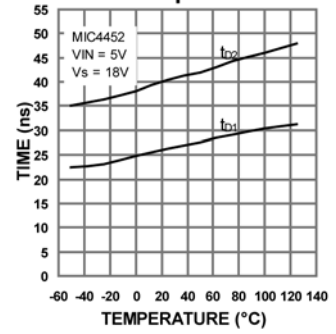
**Propagation Delay vs. Input Amplitude**



**Propagation Delay vs. Input Amplitude**



**Propagation Delay vs. Temperature**



## Applications Information

### Supply Bypassing

Charging and discharging large capacitive loads quickly requires large currents. For example, changing a 10,000pF load to 18V in 50ns requires 3.6A.

The MIC4451/4452 has double bonding on the supply pins, the ground pins and output pins. This reduces parasitic lead inductance. Low inductance enables large currents to be switched rapidly. It also reduces internal ringing that can cause voltage breakdown when the driver is operated at or near the maximum rated voltage.

Internal ringing can also cause output oscillation due to feedback. This feedback is added to the input signal since it is referenced to the same ground.

To guarantee low supply impedance over a wide frequency range, a parallel capacitor combination is recommended for supply bypassing. Low inductance ceramic disk capacitors with short lead lengths (< 0.5 inch) should be used. A 1 $\mu$ F low ESR film capacitor in parallel with two 0.1 $\mu$ F low ESR ceramic capacitors, (such as AVX RAM GUARD<sup>®</sup>), provides adequate bypassing. Connect one ceramic capacitor directly between pins 1 and 4. Connect the second ceramic capacitor directly between pins 8 and 5.

### Grounding

The high current capability of the MIC4451/4452 demands careful PC board layout for best performance. Since the MIC4451 is an inverting driver, any ground lead impedance will appear as negative feedback which can degrade switching speed. Feedback is especially noticeable with slow-rise time inputs. The MIC4451 input structure includes 200mV of hysteresis to ensure clean transitions and freedom from oscillation, but attention to layout is still recommended.

Figure 4 shows the feedback effect in detail. As the MIC4451 input begins to go positive, the output goes negative and several amperes of current flow in the ground lead. As little as 0.05 $\Omega$  of PC trace resistance can produce hundreds of millivolts at the MIC4451 ground pins. If the driving logic is referenced to power ground, the effective logic input level is reduced and oscillation may result.

To insure optimum performance, separate ground traces should be provided for the logic and power connections. Connecting the logic ground directly to the MIC4451 GND pins will ensure full logic drive to the input and ensure fast output switching. Both of the MIC4451 GND pins should, however, still be connected to power ground.

### Input Stage

The input voltage level of the MIC4451 changes the quiescent supply current. The N channel MOSFET input stage transistor drives a 320 $\mu$ A current source load. With a logic "1" input, the maximum quiescent supply current is 400 $\mu$ A. Logic "0" input level signals reduce quiescent current to 80 $\mu$ A typical.

The MIC4451/4452 input is designed to provide 200mV of hysteresis. This provides clean transitions, reduces noise sensitivity, and minimizes output stage current spiking when changing states. Input voltage threshold level is approximately 1.5V, making the device TTL compatible over the full temperature and operating supply voltage ranges. Input current is less than  $\pm 10\mu$ A.

The MIC4451 can be directly driven by the TL494, SG1526/1527, SG1524, TSC170, MIC38C42, and similar switch mode power supply integrated circuits. By offloading the power-driving duties to the MIC4451/4452, the power supply controller can operate at lower dissipation. This can improve performance and reliability.

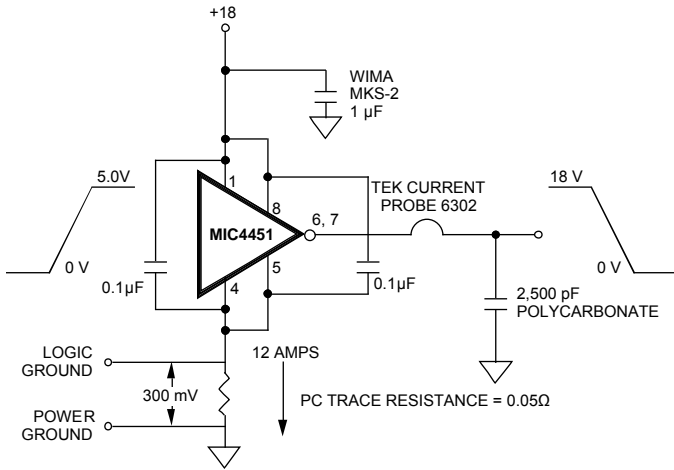
The input can be greater than the  $V_S$  supply, however, current will flow into the input lead. The input currents can be as high as 30mA p-p (6.4mA<sub>RMS</sub>) with the input. No damage will occur to MIC4451/4452 however, and it will not latch.

The input appears as a 7pF capacitance and does not change even if the input is driven from an AC source. While the device will operate and no damage will occur up to 25V below the negative rail, input current will increase up to 1mA/V due to the clamping action of the input, ESD diode, and 1k $\Omega$  resistor.

### Power Dissipation

CMOS circuits usually permit the user to ignore power dissipation. Logic families such as 4000 and 74C have outputs which can only supply a few milliamperes of current, and even shorting outputs to ground will not force enough current to destroy the device. The MIC4451/4452 on the other hand, can source or sink several amperes and drive large capacitive loads at high frequency. The package power dissipation limit can easily be exceeded. Therefore, some attention should be given to power dissipation when driving low impedance loads and/or operating at high frequency.





**Figure 4. Switching Time Degradation Due to Negative Feedback**

The supply current vs. frequency and supply current vs. capacitive load characteristic curves aid in determining power dissipation calculations. Table 1 lists the maximum safe operating frequency for several power supply voltages when driving a 10,000pF load. More accurate power dissipation figures can be obtained by summing the three dissipation sources.

Given the power dissipation in the device, and the thermal resistance of the package, junction operating temperature for any ambient is easy to calculate. For example, the thermal resistance of the 8-pin plastic DIP package, from the data sheet, is 130°C/W. In a 25°C ambient, then, using a maximum junction temperature of 125°C, this package will dissipate 960mW.

Accurate power dissipation numbers can be obtained by summing the three sources of power dissipation in the device:

- Load Power Dissipation ( $P_L$ )
- Quiescent power dissipation ( $P_Q$ )
- Transition power dissipation ( $P_T$ )

Calculation of load power dissipation differs depending on whether the load is capacitive, resistive or inductive.

**Resistive Load Power Dissipation**

Dissipation caused by a resistive load can be calculated as:

$$P_L = I^2 R_O D$$

where:

$I$  = the current drawn by the load

$R_O$  = the output resistance of the driver when the output is high, at the power supply voltage used. (See data sheet)

$D$  = fraction of time the load is conducting (duty cycle)

**Capacitive Load Power Dissipation**

Dissipation caused by a capacitive load is simply the energy placed in, or removed from, the load capacitance by the driver. The energy stored in a capacitor is described by the equation:

$$E = 1/2 C V^2$$

VS	Max. Frequency
18V	220kHz
15V	300kHz
10V	640kHz
5V	2MHz

**Table 1: MIC4451 Maximum Operating Frequency**

As this energy is lost in the driver each time the load is charged or discharged, for power dissipation calculations the 1/2 is removed. This equation also shows that it is good practice not to place more voltage on the capacitor than is necessary, as dissipation increases as the square of the voltage applied to the capacitor. For a driver with a capacitive load:

$$P_L = f C (V_S)^2$$

where:

$f$  = Operating Frequency

$C$  = Load Capacitance

$V_S$  = Driver Supply Voltage

### Inductive Load Power Dissipation

For inductive loads the situation is more complicated. For the part of the cycle in which the driver is actively forcing current into the inductor, the situation is the same as it is in the resistive case:

$$P_{L1} = I^2 R_O D$$

However, in this instance the  $R_O$  required may be either the on resistance of the driver when its output is in the high state, or its on resistance when the driver is in the low state, depending on how the inductor is connected, and this is still only half the story. For the part of the cycle when the inductor is forcing current through the driver, dissipation is best described as:

$$P_{L2} = I V_D (1 - D)$$

where  $V_D$  is the forward drop of the clamp diode in the driver (generally around 0.7V). The two parts of the load dissipation must be summed in to produce  $P_L$ :

$$P_L = P_{L1} + P_{L2}$$

### Quiescent Power Dissipation

Quiescent power dissipation ( $P_Q$ , as described in the input section) depends on whether the input is high or low. A low input will result in a maximum current drain (per driver) of  $\leq 0.2\text{mA}$ ; a logic high will result in a current drain of  $\leq 3.0\text{mA}$ . Quiescent power can therefore be found from:

$$P_Q = V_S [D I_H + (1 - D) I_L]$$

where:

$I_H$  = quiescent current with input high

$I_L$  = quiescent current with input low

$D$  = fraction of time input is high (duty cycle)

$V_S$  = power supply voltage

### Transition Power Dissipation

Transition power is dissipated in the driver each time its output changes state, because during the transition, for a very brief interval, both the N- and P-channel MOSFETs in the output totem-pole are ON simultaneously, and a current is conducted through them from  $V_S$  to ground. The transition power dissipation is approximately:

$$P_T = 2 f V_S (A \times s)$$

where ( $A \times s$ ) is a time-current factor derived from the typical characteristic curve "Crossover Energy vs. Supply Voltage." Total power ( $P_D$ ) then, as previously described is:

$$P_D = P_L + P_Q + P_T$$

### Definitions

$C_L$  = Load Capacitance in Farads.

$D$  = Duty Cycle expressed as the fraction of time the input to the driver is high.

$f$  = Operating Frequency of the driver in Hertz

$I_H$  = Power supply current drawn by a driver when both inputs are high and neither output is loaded.

$I_L$  = Power supply current drawn by a driver when both inputs are low and neither output is loaded.

$I_D$  = Output current from a driver in Amps.

$P_D$  = Total power dissipated in a driver in Watts.

$P_L$  = Power dissipated in the driver due to the driver's load in Watts.

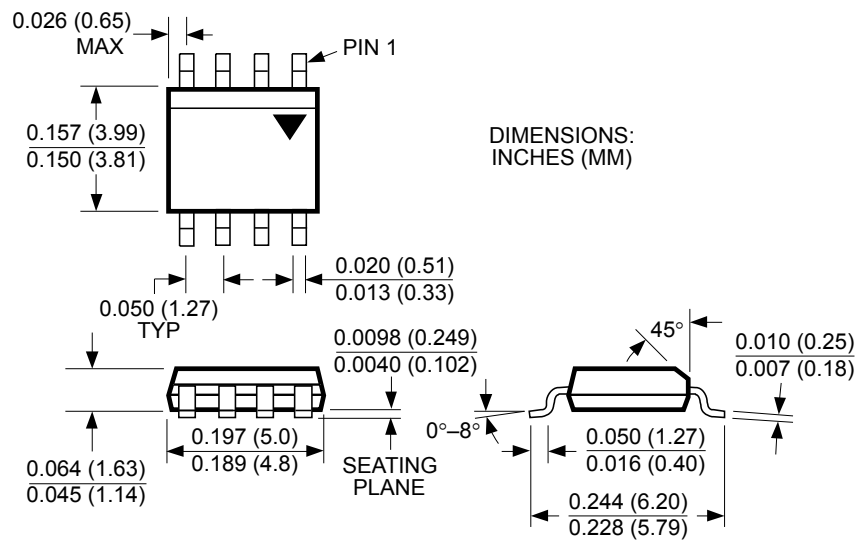
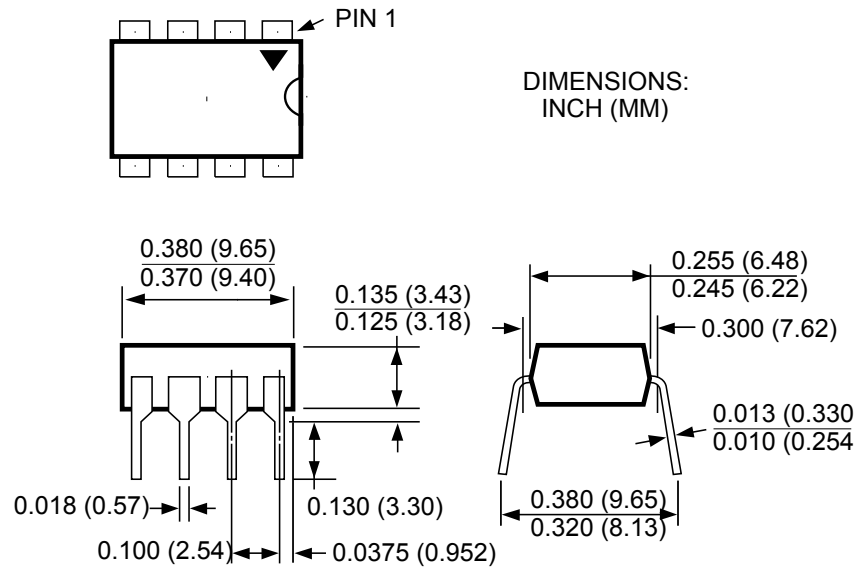
$P_Q$  = Power dissipated in a quiescent driver in Watts.

$P_T$  = Power dissipated in a driver when the output changes states ("shoot-through current") in watts.

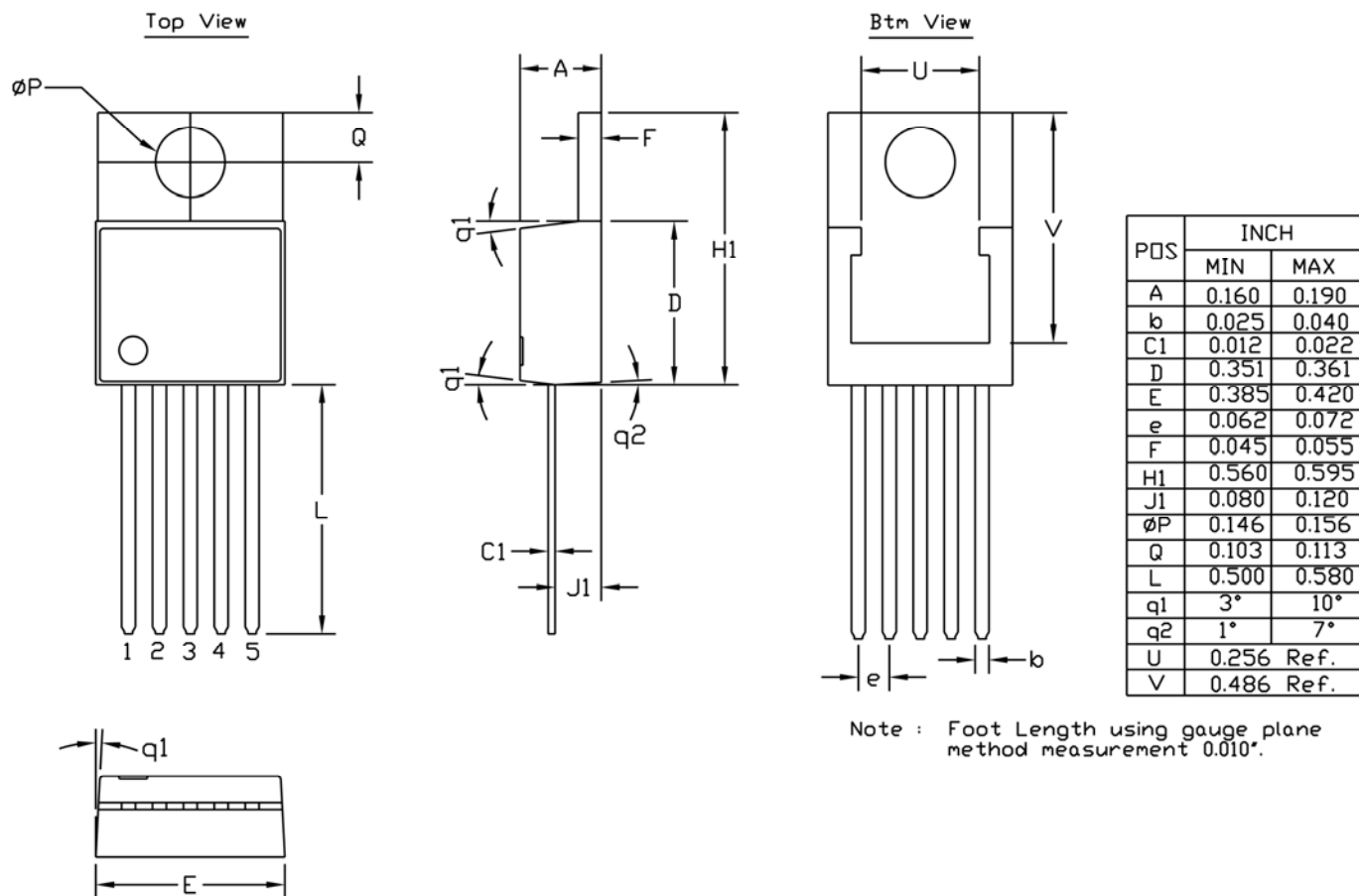
$R_O$  = Output resistance of a driver in  $\Omega$ s.

$V_S$  = Power supply voltage to the IC in volts.

## Package Information



Package Information (Continued)



5-Pin TO-220 (T)

---

**MICREL, INC. 2180 FORTUNE DRIVE SAN JOSE, CA 95131 USA**TEL +1 (408) 944-0800 FAX +1 (408) 474-1000 WEB <http://www.micrel.com>

Micrel makes no representations or warranties with respect to the accuracy or completeness of the information furnished in this data sheet. This information is not intended as a warranty and Micrel does not assume responsibility for its use. Micrel reserves the right to change circuitry, specifications and descriptions at any time without notice. No license, whether express, implied, arising by estoppel or otherwise, to any intellectual property rights is granted by this document. Except as provided in Micrel's terms and conditions of sale for such products, Micrel assumes no liability whatsoever, and Micrel disclaims any express or implied warranty relating to the sale and/or use of Micrel products including liability or warranties relating to fitness for a particular purpose, merchantability, or infringement of any patent, copyright or other intellectual property right.

Micrel Products are not designed or authorized for use as components in life support appliances, devices or systems where malfunction of a product can reasonably be expected to result in personal injury. Life support devices or systems are devices or systems that (a) are intended for surgical implant into the body or (b) support or sustain life, and whose failure to perform can be reasonably expected to result in a significant injury to the user. A Purchaser's use or sale of Micrel Products for use in life support appliances, devices or systems is a Purchaser's own risk and Purchaser agrees to fully indemnify Micrel for any damages resulting from such use or sale.

© 1998 Micrel, Incorporated.



## Стандарт Электрон Связь

Мы молодая и активно развивающаяся компания в области поставок электронных компонентов. Мы поставляем электронные компоненты отечественного и импортного производства напрямую от производителей и с крупнейших складов мира.

Благодаря сотрудничеству с мировыми поставщиками мы осуществляем комплексные и плановые поставки широчайшего спектра электронных компонентов.

Собственная эффективная логистика и склад в обеспечивает надежную поставку продукции в точно указанные сроки по всей России.

Мы осуществляем техническую поддержку нашим клиентам и предпродажную проверку качества продукции. На все поставляемые продукты мы предоставляем гарантию .

Осуществляем поставки продукции под контролем ВП МО РФ на предприятия военно-промышленного комплекса России , а также работаем в рамках 275 ФЗ с открытием отдельных счетов в уполномоченном банке. Система менеджмента качества компании соответствует требованиям ГОСТ ISO 9001.

Минимальные сроки поставки, гибкие цены, неограниченный ассортимент и индивидуальный подход к клиентам являются основой для выстраивания долгосрочного и эффективного сотрудничества с предприятиями радиоэлектронной промышленности, предприятиями ВПК и научно-исследовательскими институтами России.

С нами вы становитесь еще успешнее!

### Наши контакты:

**Телефон:** +7 812 627 14 35

**Электронная почта:** [sales@st-electron.ru](mailto:sales@st-electron.ru)

**Адрес:** 198099, Санкт-Петербург,  
Промышленная ул, дом № 19, литера Н,  
помещение 100-Н Офис 331